

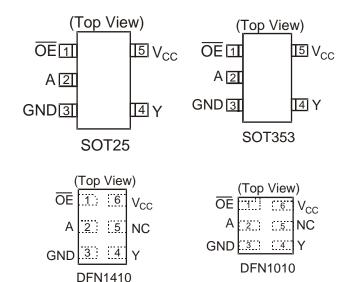
Description

The 74LVC1G125 is a single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a HIGH-level is applied to the output enable (\overline{OE}) pin. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

Features

- Wide Supply Voltage Range from 1.65 to 5.5V
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- I_{OFF} Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Tested per JESD 22
 - o Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- Direct Interface with TTL Levels
- All packages Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

Pin Assignments



Applications

- Voltage Level Shifting
- Bus Driver / Repeater
- Power Down Signal Isolation
- General Purpose Logic
- Wide array of products such as:
 - PCs, networking, notebooks, netbooks, PDAs
 - Tablet Computers, E-readers
 - Computer peripherals, hard drives, CD/DVD ROM
 - o TV, DVD, DVR, set top box
 - o Cell Phones, Personal Navigation / GPS
 - o MP3 players ,Cameras, Video Recorders

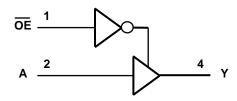
Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html



Pin Descriptions

Pin Name	Description	
ŌE	Output Enable	
Α	Data Input	
GND	Ground	
Υ	Data Output	
V _{CC}	Supply Voltage	
NC	No Connection	

Logic Diagram



Function Table

Inp	Output	
OE	Α	Υ
L	Н	Н
L	L	L
Н	X	Z

Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I _{OFF} state	-0.5 to 6.5	٧
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	٧
I _{IK}	Input Clamp Current V _I <0	-50	mA
I _{OK}	Output Clamp Current	-50	mA
I _O	Continuous output current	±50	mA
I _{CC} , I _{GND}	Continuous current through Vcc or GND	±100	mA
T_J	Operating Junction Temperature	-40 to 150	°C
T _{STG}	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 3)

Symbol		Parameter	Min	Max	Unit
\/aa	Operating Voltage	Operating	1.65	5.5	V
V _{CC}	Operating Voltage	Data retention only	1.5		V
		$V_{CC} = 1.65V \text{ to } 1.95V$	0.65 X V _{CC}		
V	High-level Input Voltage	$V_{CC} = 2.3V \text{ to } 2.7V$	1.7		V
V _{IH}	High-level input voltage	$V_{CC} = 3V$ to 3.6V	2		V
		$V_{CC} = 4.5V \text{ to } 5.5V$	0.7 X V _{CC}		
		V _{CC} = 1.65V to 1.95V		0.35 X V _{CC}	
\ /	Levelevel import veltage	$V_{CC} = 2.3V \text{ to } 2.7V$		0.7	M
V_{IL}	Low-level input voltage	V _{CC} = 3V to 3.6V		0.8	V
		V _{CC} = 4.5V to 5.5V		0.3 X V _{CC}	
VI	Input Voltage	•	0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
	I _{OH} High-level output current	V _{CC} = 1.65V		-4	
		V _{CC} = 2.3V		-8	
I_{OH}		V 2V		-16	mA
		$V_{CC} = 3V$		-24	
		$V_{CC} = 4.5V$		-32	
		V _{CC} = 1.65V		4	
		V _{CC} = 2.3V		8	
I_{OL}	Low-level output current	V _{CC} = 3V		16	mA
		ACC = 2A		24	
		$V_{CC} = 4.5V$		32	
	land the cities size as fall	$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$		20	
$\Delta t/\Delta V$	Input transition rise or fall rate	$V_{CC} = 3.3V \pm 0.3V$		10	ns/V
	rate	$V_{CC} = 5V \pm 0.5V$		5	
T _A	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at $V_{\mbox{CC}}$ or Ground.



Electrical Characteristics (All typical values are at V_{CC} = 3.3V, T_A = 25°C)

0 1 1		Total Constitution	.,	-40	°C to 85°0	C	-40°C to	125°C	I Imit
Symbol	Parameter	Test Conditions	V _{CC}	Min	Тур.	Max	Min	Max	Unit
		I _{OH} = -100μA	1.65V to 5.5V	V _{CC} – 0.1			V _{CC} – 0.1		
		I _{OH} = -4mA	1.65V	1.2			0.95		
V _{OH}	High Level Output	$I_{OH} = -8mA$	2.3V	1.9			1.7		V
VOH	Voltage	I _{OH} = -16mA	3V	2.4			2.2		V
	l	I _{OH} = -24mA	3 V	2.3			2.0		
		I _{OH} = -32mA	4.5V	3.8			3.4		
		I _{OL} = 100μA	1.65V to 5.5V			0.1		0.1	
	l	I _{OL} = 4mA	1.65V			0.45		0.7	
V _{OL}	Low Level Output	I _{OL} = 8mA	2.3V			0.3		0.45	V
VOL	Voltage	I _{OL} = 16mA	3V			0.4		0.6	V
	lage	I _{OL} = 24mA	3 v			0.55		0.8	
		$I_{OL} = 32mA$	4.5V			0.55		.8	
II	Input Current	$V_I = 5.5 \text{ V or GND}$	0 to 5.5V		± 0.1	±5		± 100	μΑ
I _{OFF}	Power Down Leakage Current	V_I or $V_O = 5.5V$	0V			±10		±200	μΑ
l _{OZ}	Z State Leakage Current	V _O =0 to 5.5V	3.6V		0.1	10		20	μА
I _{CC}	Supply Current	$V_I = 5.5V$ or GND $I_O=0$	5.5V		0.1	10		200	μΑ
ΔI _{CC}	Additional Supply Current	One input at V _{CC} – 0.6V Other inputs at V _{CC} or GND	3V to 5.5V			500		5000	μΑ
C _i	Input Capacitance	$V_i = V_{CC} - \text{or GND}$	3.3V		5				pF

Operating Characteristics

 $T_A = 25$ °C

Parameter		Test	V _{CC} = 1.8V	$V_{CC} = 2.5V$	$V_{CC} = 3.3V$	V _{CC} = 5V	Unit	
	raiailletei		Conditions	Тур.	Тур.	Тур.	Тур.	O I II
	Power	Outputs enabled	£ 40 MH=	19	19	19	21	ו
C _{pd}	dissipation capacitance	Outputs disabled	f = 10 MHz	2	2	3	4	pF



Package Characteristics (All typical values are at V_{CC} = 3.3V, T_A = 25°C)

Symbol	Parameter	Test Conditions	V _{CC}	Min	Тур.	Max	Unit	
		SOT25			204			
0	Junction-to-Ambient	SOT353	(Note 4)		371		°C/W	
θ _{JA}		DFN1010	(Note 4)		445			
		DFN1410			460			
		SOT25			52			
0	Thermal Resistance Junction-to-Case	SOT35	(NI=4= 4)		143		°C/W	
θ_{JC}		DFN1010	(Note 4)		250			
		DFN1410			265			

Notes:

Switching Characteristics

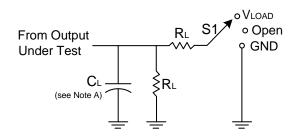
Figure 1 Typical Values at T_A = 25 °C and nominal voltages 1.8V, 2.5V, 2.7V, 3.3V, and 5.0V.

Doromotor	From	То	V	T _A	= -40°C to 8	5ºC	$T_A = -40^{\circ}C$	C to 125°C	Heit
Parameter	Input	Output	V _{CC}	Min	Тур	Max	Min	Max	Unit
			1.8V ± 0.15V	1.0	3.3	8.0	1.0	10.5	
			$2.5V \pm 0.2V$	0.5	2.2	5.5	0.5	7.0	
t _{pd}	Α	Υ	2.7V	0.5	2.5	5.5	0.5	7.5	ns
·			$3.3V \pm 0.3V$	0.5	2.1	4.5	0.5	6.0	
			$5.0V \pm 0.5V$	0.5	1.7	4.0	0.5	5.5	
	ŌĒ		1.8 V ± 0.15V	1.0	4.1	9.4	1.0	12.0	
			$2.5V \pm 0.2V$	0.5	2.8	6.6	0.5	8.5	
t _{en}		Υ	2.7V	0.5	3.3	6.6	0.5	8.5	ns
			$3.3V \pm 0.3V$	0.5	2.4	5.3	0.5	7.0	
			$5.0V \pm 0.5V$	0.5	2.1	5.0	0.5	6.5	
			1.8V ± 0.15V	1.0	4.3	9.2	1.0	12.0	
		Y	$2.5V \pm 0.2V$	0.5	2.7	5.0	0.5	6.5	
t _{dis}	OE		2.7V	0.5	3.0	5.0	0.5	6.5	ns
			$3.3V \pm 0.3V$	0.5	3.1	5.0	0.5	6.5	
			5.0V ± 0.5V	0.5	2.2	4.2	0.5	5.5	

^{4.} Test condition for SOT25, SOT353, DFN1410 and DFN1010: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

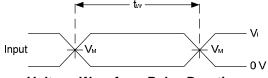


Parameter Measurement Information

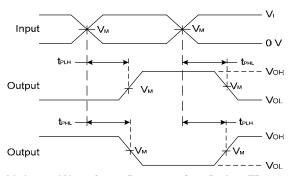


TEST	S 1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	Vload
t _{PHZ} /t _{PZH}	GND

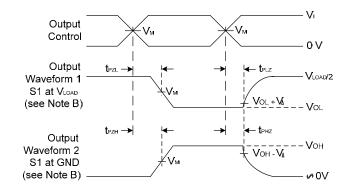
Vcc	Inputs		V V		•	В	V Δ
VCC	VI	t _r /t _f	V _M	V _{LOAD}	CL	R_L	VΔ
1.8V±0.15V	V _{CC}	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	1ΚΩ	0.15V
2.5V±0.2V	V _{CC}	≤2ns	V _{CC} /2	2 X V _{CC}	30pF	500Ω	0.15V
2.7V	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
5V±0.5V	V _{CC}	≤2.5ns	V _{CC} /2	2 X V _{CC}	50pF	500Ω	0.3V



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times
Low and High Level Enabling

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.

C. Inputs are measured separately one transition per measurement.

D. t_{PLZ} and t_{PHZ} are the same as t_{dis.}

E. t_{PZL} and t_{PZH} are the same as t_{EN}.

F. t_{PLH} and t_{PHL} are the same as $t_{PD.}$



Ordering Information

74LVC1G 125 XXX - 7

Logic Device **Function** Package Packing 74: Logic Prefix W5: SOT25 7: Tape & Reel

125:3-State Buffer LVC: 1.65 to 5.5V Family

1G: One gate

SE: SOT353 OE - Low FW4: DFN1010 FZ4: DFN1410

Device	Package	Packaging	7" Tape a	and Reel
Device	Code	(Note 6)	Quantity	Part Number Suffix
74LVC1G125W5-7	W5	SOT25	3000/Tape & Reel	-7
74LVC1G125SE-7	SE	SOT353	3000/Tape & Reel	-7
74LVC1G125FW4-7	FW4	DFN1010	5000/Tape & Reel	-7
74LVC1G125FZ4-7	FZ4	DFN1410	5000/Tape & Reel	-7

5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at Notes: http://www.diodes.com/datasheets/ap02001.pdf

6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SOT25 and SOT353

(Top View)

XX Y W X

2

XX: Identification Code

Y: Year 0~9

W: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents 52 and 53 week

X: A~Z: Internal Code

Part Number	Package	Identification Code
74LVC1G125W5	SOT25	UY
74LVC1G125SE	SOT353	UY

(2) DFN1010 and DFN1410

(Top View)

XX <u>Y W X</u> XX: Identification Code

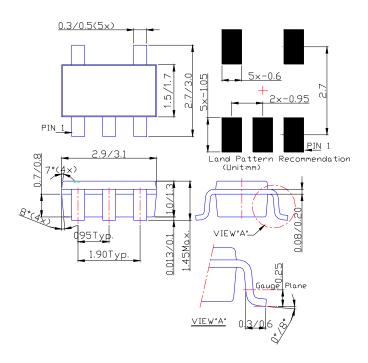
Y : Year 0~9 W : Week : A~Z : 1~26 week; a~z: 27~52 week; z represents 52 and 53 week X: A~Z: Internal Code

Part Number	Package	Identification Code
74LVC1G125FW4	DFN1010	UY
74LVC1G125FZ4	DFN1410	UY

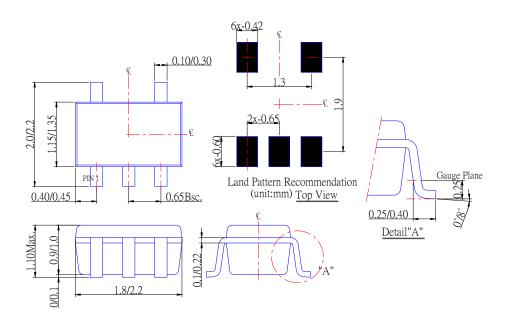


Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



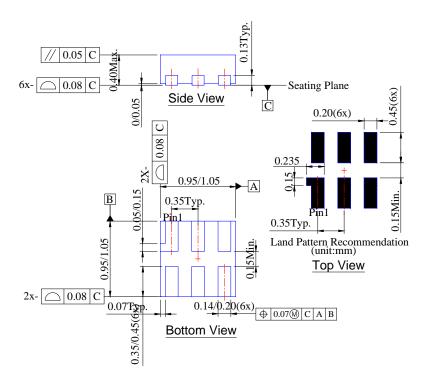
(2) Package Type: SOT353



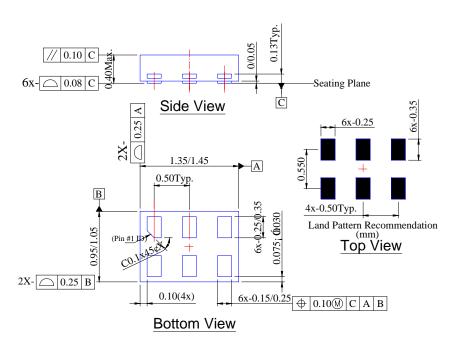


Package Outline Dimensions (cont.)

(3) Package Type DFN1010



(4) Package Type: DFN1410





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